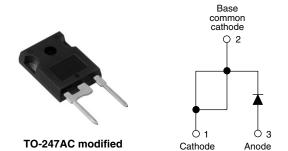


## Vishay High Power Products

# Hyperfast Rectifier, 30 A FRED Pt<sup>TM</sup>



# PRODUCT SUMMARY t<sub>rr</sub> (typical) 28 ns I<sub>F(AV)</sub> 30 A V<sub>R</sub> 600 V

#### **FEATURES**

- · Hyperfast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- · Single diode device
- Designed and qualified for industrial level

#### **DESCRIPTION/APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	$V_{RRM}$		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 116 °C	30	Δ.		
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	300	Α		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	2.0	2.6	V
	٧F	I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	=	1.34	1.75	
Reverse leakage current		V <sub>R</sub> = V <sub>R</sub> rated	-	0.3	50	
	I <sub>R</sub>	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	=	60	500	μΑ
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	=	33	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body -		3.5	-	nH

Document Number: 93017 Revision: 02-Jun-08

## 30EPH06

## Vishay High Power Products

#### Hyperfast Rectifier, 30 A FRED Pt<sup>TM</sup>



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt =$	= 50 A/μs, V <sub>R</sub> = 30 V	-	28	35	ns
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_B = 200 \text{ V}$	=	31	-	
		T <sub>J</sub> = 125 °C		=	77	-	
Peak recovery current	1	T <sub>J</sub> = 25 °C		-	3.5	-	А
	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		=	7.7	-	
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		=	65	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	345	-	110

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C	
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	0.5	0.9		
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased - 0.4		-			
Weight			-	6.0	-	g	
			-	0.22	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC modified	30EPH06				

Document Number: 93017 Revision: 02-Jun-08



# Hyperfast Rectifier, 30 A FRED Pt<sup>TM</sup>

### Vishay High Power Products

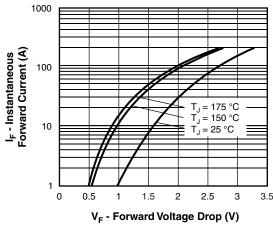


Fig. 1 - Typical Forward Voltage Drop Characteristics

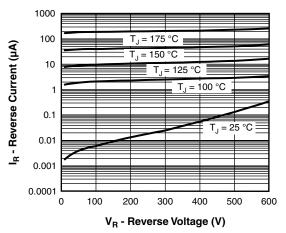


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

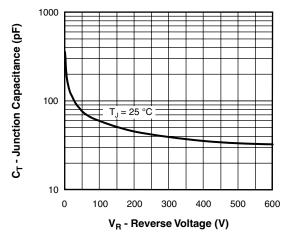


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

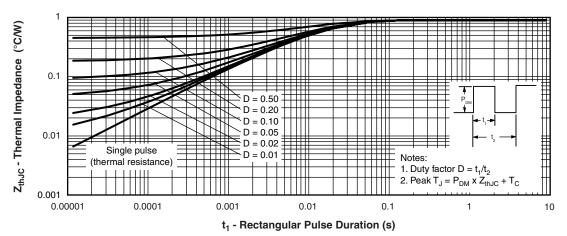


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

#### Vishay High Power Products

# Hyperfast Rectifier, 30 A FRED Pt<sup>TM</sup>



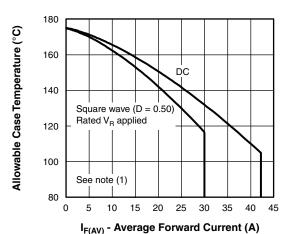


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

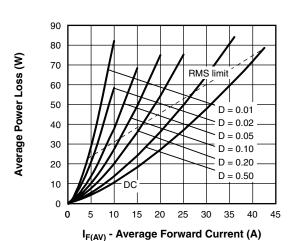


Fig. 6 - Forward Power Loss Characteristics

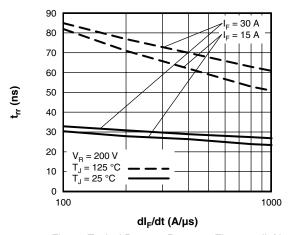


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

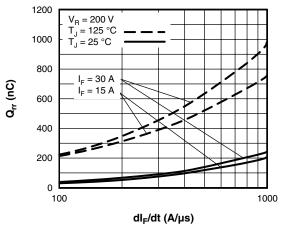


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} \;\; \text{Formula used:} \; T_C = T_J - (Pd + Pd_{REV}) \; x \; R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \; x \; V_{FM} \; \text{at} \; (I_{F(AV)}/D) \; (\text{see fig. 6}); \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \; x \; I_R \; (1 - D); \; I_R \; \text{at} \; V_{R1} = \text{Rated} \; V_R \\ \end{array}$ 



# Hyperfast Rectifier, 30 A FRED Pt<sup>TM</sup>

## Vishay High Power Products

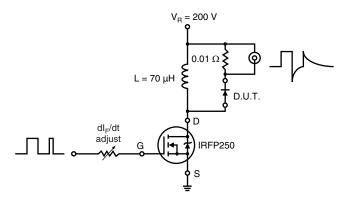
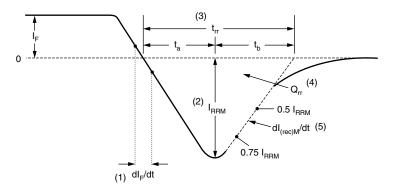


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $\rm I_{RRM}$  peak reverse recovery current
- (3)  $t_{\rm rr}$  reverse recovery time measured from zero crossing point of negative going  $I_{\rm F}$  to point where a line passing through 0.75  $I_{\rm RRM}$  and 0.50  $I_{\rm RRM}$  extrapolated to zero current.
- (4)  $\rm Q_{rr}$  area under curve defined by  $\rm t_{rr}$  and  $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

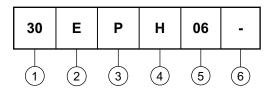
Vishay High Power Products

Hyperfast Rectifier, 30 A FRED Pt<sup>TM</sup>



#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Current rating (30 = 30A)

2 - Circuit configuration:

E = Single diode

3 - Package:

P = TO-247AC modified

- H = Hyperfast recovery

Voltage rating (06 = 600V)

6 - None = Standard production

• PbF = Lead (Pb)-free

Tube standard pack quantity: 25 pieces

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95253					
Part marking information	http://www.vishay.com/doc?95255				

Document Number: 93017 Revision: 02-Jun-08



Vishay

#### **Disclaimer**

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 Revision: 18-Jul-08